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U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE
U.S. Patent and Trademark Office; U.S. DEPARTMENT OF COMMERCE
Application Number

Application Number Filing Date **TRANSMITTAL** November 25, 2003 First Named Inventor **FORM** Nobuyuki SEKIKAWA Art Unit 2814 (to be used for all correspondence after initial filing)

Examiner Name S. Rao Attorney Docket Number Total Number of Pages in This Submission 4 492322001810

ENCLOSURES (Check all that apply)				
Fee Transmittal Form		Drawing(s)		After Allowance Communication to TC
Fee Attached		Licensing-related Papers		Appeal Communication to Board of Appeals and Interferences
X Amendment/Reply		Petition		Appeal Communication to TC (Appeal Notice, Brief, Reply Brief)
After Final		Petition to Convert to a Provisional Application		Proprietary Information
Affidavits/declaration(s)		Power of Attorney, Revocation Change of Correspondence Address		Status Letter
Extension of Time Request		Terminal Disclaimer		X Other Enclosure(s) (please Identify below):
Express Abandonment Request		Request for Refund		Return Receipt Postcard
Information Disclosure Statement		CD, Number of CD(s)		
Certified Copy of Priority Document(s)		Landscape Table on CD		
Reply to Missing Parts/ Incomplete Application		Remarks		
Reply to Missing Parts under 37 CFR 1.52 or 1.53				
SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT				
Firm Name	e MORRISON & FOERSTER LLP			
Signature	Reference.			
Printed name	Barry E. Bretschneider			
Date May 24, 2005		Reg. No.	28,055	



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In the application of:

Nobuyuki SEKIKAWA et al.

Serial No.:

10/720,378

Filing Date: November 25, 2003

METHOD OF MANUFACTURING

INSULATED GATE

SEMICONDUCTOR DEVICE

Examiner: S. Rao

Group Art Unit: 2814

RESPONSE UNDER 37 CFR 1.111

M/S Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

In response to the Action mailed February 24, 2005, please reconsider this application in light of following remarks:

REMARKS

Claims 6-11 have been rejected under 35 USC 103(a) as unpatentable over U.S. Patent No. 5,397,909 (Moslehi) in view of U. S. Patent No. 5,882,994 (Araki). Applicants respectfully traverse this rejection.

Claim 6 recites forming a field oxidation film and a second gate oxide film through selective oxidation by using the oxidation protection film as a mask. The Examiner contends that Moslehi's interim gate etch-stop layer 52 corresponds to the claimed oxidation protection film and Moslehi's field insulating region 42 to the claimed field oxidation film and concludes va-109142